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PATENT

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants	Michael Heuken, <i>et al.</i>
Serial No. 09/873,041	Filing Date: June 1, 2001
Title of Application:	Method And System For Semiconductor Crystal Production With Temperature Management
Confirmation No. 5097	Group Art Unit: 1765
Examiner	Matthew J. Song

Assistant Commissioner for Patents
Washington, DC 20231

Response to Official Action of February 26, 2003

Dear Sir:

In response to the non-final Official Action mailed on February 26, 2003 in the above U.S. patent application, Applicants herewith present Amendments thereto and request reconsideration of all outstanding rejections found therein.

Amendments

In the Claims

A Marked Up Version of Amended Claims 1 - 17 is Set Forth Below:

1. (Amended) A [Method] method of producing nitrogenous semiconductor crystal materials [and particularly] in the nature of strata on a wafer[s] of the form $A_xB_yC_zN_vM_w$, wherein A, B[,] and C represent elements of elemental group II group

Mailing Certificate: I hereby certify that this correspondence is today being deposited with the U.S. Postal Service as *First Class Mail* in an envelope addressed to: Commissioner for Patents and Trademarks; Washington, DC 20231.

April 24, 2003


Caroline Gahagan

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